

R-C Thermal Model Parameters

DESCRIPTION

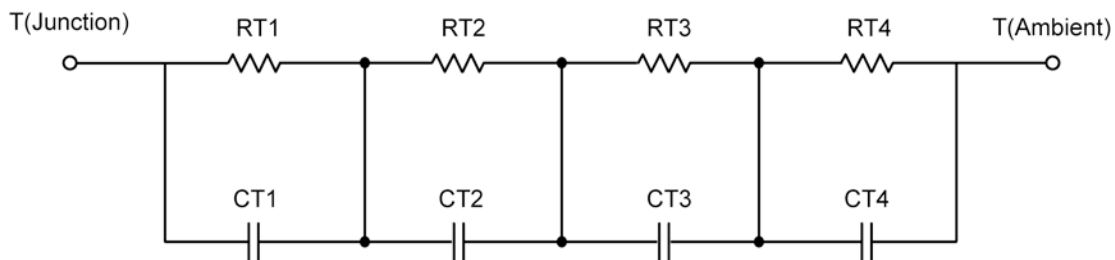
The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

For a detailed explanation of implementing these values in P-Spice, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-Spice Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



| R-C VALUES FOR TANK CONFIGURATION | | | |
|-----------------------------------|---------|------------|------|
| Thermal Resistance (°C/W) | | | |
| Junction to | Ambient | Case | Foot |
| RT1 | N/A | 47.6767 m | N/A |
| RT2 | N/A | 19.4185 m | N/A |
| RT3 | N/A | 299.9507 m | N/A |
| RT4 | N/A | 182.9541 m | N/A |
| Thermal Capacitance (Joules/°C) | | | |
| Junction to | Ambient | Case | Foot |
| CT1 | N/A | 19.2596 m | N/A |
| CT2 | N/A | 7.8658 m | N/A |
| CT3 | N/A | 171.3153 m | N/A |
| CT4 | N/A | 50.7447 m | N/A |

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION



| R-C VALUES FOR FILTER CONFIGURATION | | | |
|--|---------|------------|------|
| Thermal Resistance (°C/W) | | | |
| Junction to | Ambient | Case | Foot |
| RF1 | N/A | 109.0293 m | N/A |
| RF2 | N/A | 131.7538 m | N/A |
| RF3 | N/A | 116.8807 m | N/A |
| RF4 | N/A | 192.3362 m | N/A |
| Thermal Capacitance (Joules/°C) | | | |
| Junction to | Ambient | Case | Foot |
| CF1 | N/A | 8.9025 m | N/A |
| CF2 | N/A | 32.1198 m | N/A |
| CF3 | N/A | 4.8889 m | N/A |
| CF4 | N/A | 207.3418 m | N/A |

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

